
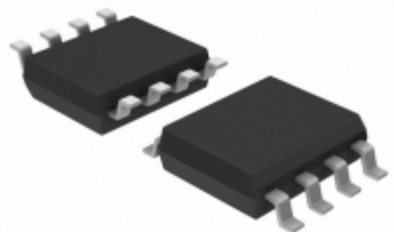









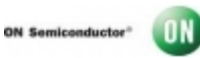
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|  | <h2 style="color: red;">NTMSD6N303R2</h2> | |
| | Hersteller-Teilenummer: | NTMSD6N303R2 |
|  | Hersteller / Marke: | AMI Semiconductor / ON Semiconductor |
| | Teil der Beschreibung: | MOSFET N-CH 30V 6A 8-SOIC |
|  | Datenblätter: |  NTMSD6N303R2.pdf |
| | RoHs Status: | Enthält Blei / RoHS nicht konform |
| Lagerzustand: | New original, 1121 pcs Stock Available. | |
| Liefern von: | Hong Kong | |
| Versandweg: | DHL/Fedex/TNT/UPS/EMS | |
| Image may be representation. See specs for product details. | | |

Spezifikationen

| | |
|---|---|
| Teilenummer | NTMSD6N303R2 |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 30V 6A 8-SOIC |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 1121 pcs Stock |
| Serie | FETKY™ |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | 8-SOIC (0.154", 3.90mm Width) |
| Supplier Device-Gehäuse | 8-SOIC |
| Verlustleistung (max) | 2W (Ta) |
| Typ FET | N-Channel |
| FET-Merkmal | Schottky Diode (Isolated) |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 6A (Ta) |
| Rds On (Max) @ Id, Vgs | 32 mOhm @ 6A, 10V |
| VGS (th) (Max) @ Id | 2.5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 30nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 950pF @ 24V |
| Verpackung | Tape & Reel (TR) |

NTMSD6N303R2 ist neu im Original, Suche NTMSD6N303R2 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTMSD6N303R2 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTMSD6N303R2: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|---|---|---|
|  <p>NTMSD3P102R2G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.34A 8-SOIC</p> |  <p>NTMSD3P303R2 ON NTMSD3P303R2 ON</p> |  <p>NTMSD3P102R2SG AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 2.34A 8-SOIC</p> |  <p>NTMSD3P303R2G AMI Semiconductor / ON Semiconductor MOSFET P-CH 30V 2.34A 8-SOIC</p> |
|  <p>NTMSD6N303R2G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6A 8-SOIC</p> |  <p>NTMSD6N03R2G ON NTMSD6N03R2G ON</p> |  <p>NTMSD6N303R2SG AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 6A 8-SOIC</p> |  <p>NTMSD3P303DR2G AMI Semiconductor / ON Semiconductor NTMSD3P303DR2G ON</p> |

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Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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